

Vision of the Institution

To ignite the minds of the students through academic excellence so as to bring about social transformation and prosperity.

Mission of the Institution

- To expand the frontiers of knowledge through Quality Education.
- To provide valued added Research and Development.
- To embody a spirit of excellence in Teaching, Creativity, Scholarship and Outreach.
- To provide a platform for synergy of Academy, Industry and Community.
- To inculcate high standards of Ethical and Professional Behavior.

Vision of ECE Department

In pursuit of world class excellence in the field of Electronics & Communication Engineering by imparting quality education and promoting Research.

Mission of ECE Department

- To empower students with knowledge and competencies in the field of Electronics & Communication Engineering conforming to International standards.
- To produce creative solutions essential to local and global needs in the field of Electronics & Communication Engineering.
- To mould the students professionally with a consciousness of moral values and professional ethical code.

Program Educational Objectives (PEOs) of ECE Department

PEO1: To provide world class Education in the principles of engineering that incorporate open ended design experience and the use of software and hardware tools related to Electronics and Communication Engineering and hence improve the employability skills of the student.

PEO2: To make the students able to function with multi-disciplinary teams that will enhance the leadership qualities and to formulate and solve engineering problems as a team which helps the student to adopt better professional conduct.

PEO3: To provide learning environment that provides open interaction for the students with faculty and staff that makes them innovative and dynamic and encourages research and motivate them to solve the problems of the society.

Program Outcomes (POs) of ECE Department

Engineering Graduates will be able to:

1. **Engineering knowledge:** Apply the knowledge of mathematics, science, engineering fundamentals, and an engineering specialization to the solution of complex engineering problems.
2. **Problem analysis:** Identify, formulate, review research literature, and analyze complex engineering problems reaching substantiated conclusions using first principles of mathematics, natural sciences, and engineering sciences.
3. **Design/development of solutions:** Design solutions for complex engineering problems and design system components or processes that meet the specified needs with appropriate consideration for the public health and safety, and the cultural, societal, and environmental considerations.
4. **Conduct investigations of complex problems:** Use research-based knowledge and research methods including design of experiments, analysis and interpretation of data, and synthesis of the information to provide valid conclusions.
5. **Modern tool usage:** Create, select, and apply appropriate techniques, resources, and modern engineering and IT tools including prediction and modeling to complex engineering activities with an understanding of the limitations.
6. **The engineer and society:** Apply reasoning informed by the contextual knowledge to assess societal, health, safety, legal and cultural issues and the consequent responsibilities relevant to the professional engineering practice.
7. **Environment and sustainability:** Understand the impact of the professional engineering solutions in societal and environmental contexts, and demonstrate the knowledge of, and need for sustainable development.
8. **Ethics:** Apply ethical principles and commit to professional ethics and responsibilities and norms of the engineering practice.
9. **Individual and team work:** Function effectively as an individual, and as a member or leader in diverse teams, and in multidisciplinary settings.
10. **Communication:** Communicate effectively on complex engineering activities with the engineering community and with society at large, such as, being able to comprehend and write effective reports and design documentation, make effective presentations, and give and receive clear instructions.

11. **Project management and finance:** Demonstrate knowledge and understanding of the engineering and management principles and apply these to one's own work, as a member and leader in a team, to manage projects and in multidisciplinary environments.
12. **Life-long learning:** Recognize the need for, and have the preparation and ability to engage in independent and life-long learning in the broadest context of technological change.

Program Specific Outcomes (PSOs) of ECE Department

1. Will be equipped with knowledge of innovative, dynamic complete design flow specialized in implementation of projects pertaining to communication system, signal processing, digital and analog IC design, embedded systems and will integrate all areas to illustrate the goal of digital India.
2. Will have the ability to analyze, design electronics and communication applications using software tools like, pSpice, XYLINX, MATLAB, Mentor Graphics and other related software's.
3. Can demonstrate the principles of semiconductor devices, digital system, Microprocessor and microcontrollers, signal processing, antenna design in fields of consumer electronics, medical, defence and spacecraft electronics industry.
4. Will have strong ethical moral values and sound fundamental foundation of technical knowledge in all core subjects which help them to explore scientific theories, ideas, methods and technologies that help in solving current and future universal societal problems through Assistive Technology Laboratory as a flat form.

II Year - I Semester

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ELECTRONIC DEVICES AND CIRCUITS

Objectives:

The main objectives of this course are:

- The basic concepts of semiconductor physics are to be reviewed.
- Study the physical phenomena such as conduction, transport mechanism and electrical characteristics of different diodes.
- The application of diodes as rectifiers with their operation and characteristics with and without filters are discussed.
- The principal of working and operation of Bipolar Junction Transistor and Field Effect Transistor and their characteristics are explained.
- The need of transistor biasing and its significance is explained. The quiescent point or operating point is explained.
- Small signal equivalent circuit analysis of BJT and FET transistor amplifiers in different configuration is explained.

Syllabus:

UNIT-I:Semi Conductor Physics : Insulators, Semi conductors, and Metals classification using energy band diagrams, mobility and conductivity, electrons and holes in intrinsic semi conductors, extrinsic semi conductors, drift and diffusion, charge densities in semiconductors, Hall effect, continuity equation, law of junction, Fermi Dirac function, Fermi level in intrinsic and extrinsic Semiconductors

UNIT- II: Junction Diode Characteristics : Open circuited p-n junction, Biased p-n junction, p-n junction diode, current components in PN junction Diode, diode equation, V-I Characteristics, temperature dependence on V-I characteristics, Diode resistance, Diode capacitance, energy band diagram of PN junction Diode.

Special Semiconductor Diodes: Zener Diode, Breakdown mechanisms, Zener diode applications, LED, Photo diode, Tunnel Diode, SCR, UJT. Construction, operation and characteristics of all the diodes are required to be considered.

UNIT- III: Rectifiers and Filters: Basic Rectifier setup, half wave rectifier, full wave rectifier, bridge rectifier, derivations of characteristics of rectifiers, rectifier circuits-operation, input and output waveforms, Filters, Inductor filter, Capacitor filter, comparison of various filter circuits in terms of ripple factors.

UNIT- IV: Transistor Characteristics:

BJT: Junction transistor, transistor current components, transistor equation, transistor configurations, transistor as an amplifier, characteristics of transistor in Common Base, Common Emitter and Common Collector configurations, Ebers-Moll model of a transistor, punch through/ reach through, Photo transistor, typical transistor junction voltage values.

FET: FET types, construction, operation, characteristics, parameters, MOSFET-types, construction, operation, characteristics, comparison between JFET and MOSFET.

UNIT- V: Transistor Biasing and Thermal Stabilization : Need for biasing, operating point, load line analysis, BJT biasing- methods, basic stability, fixed bias, collector to base bias, self bias, Stabilization against variations in V_{BE} , I_c , and β , Stability factors, (S, S', S'') , Bias compensation, Thermal runaway, Thermal stability.

FET Biasing- methods and stabilization.

UNIT- VI: Small Signal Low Frequency Transistor Amplifier Models:

BJT: Two port network, Transistor hybrid model, determination of h-parameters, conversion of h-parameters, generalized analysis of transistor amplifier model using h-parameters, Analysis of CB, CE and CC amplifiers using exact and approximate analysis, Comparison of transistor amplifiers.

FET: Generalized analysis of small signal model, Analysis of CG, CS and CD amplifiers, comparison of FET amplifiers.

Text Books:

1. Electronic Devices and Circuits- J. Millman, C. Halkias, Tata Mc-Graw Hill, Second Edition.
2. Integrated Electronics- Jacob Millman, C. Halkies, C.D.Parikh, Tata Mc-Graw Hill, 2009.

References:

1. Electronic Devices and Circuits-K. Satya Prasad, VGS Book Links.
2. Electronic Devices and Circuits-Salivahanan, Kumar, Vallavaraj, Tata Mc-Graw Hill, Second Edition
3. Electronic Devices and Circuits – Bell, Oxford

Outcomes:

At the end of this course the student can able to:

- Understand the basic concepts of semiconductor physics.
- Understand the formation of p-n junction and how it can be used as a p-n junction as diode in different modes of operation.
- Know the construction, working principle of rectifiers with and without filters with relevant expressions and necessary comparisons.
- Understand the construction, principle of operation of transistors, BJT and FET with their V-I characteristics in different configurations.
- Know the need of transistor biasing, various biasing techniques for BJT and FET and stabilization concepts with necessary expressions.
- Perform the analysis of small signal low frequency transistor amplifier circuits using BJT and FET in different configurations.

II Year - I Semester

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SWITCHING THEORY AND LOGIC DESIGN

UNIT – I: REVIEW OF NUMBER SYSTEMS & CODES:

- i) Representation of numbers of different radix, conversion from one radix to another radix, $r-1$'s compliments and r 's compliments of signed members, problem solving.
- ii) 4 bit codes, BCD, Excess-3, 2421, 84-2-1 9 's complement code etc.,
- iii) Logic operations and error detection & correction codes; Basic logic operations -NOT, OR, AND, Universal building blocks, EX-OR, EX-NOR - Gates, Standard SOP and POS, Forms, Gray code, error detection, error correction codes (parity checking, even parity, odd parity, Hamming code) NAND-NAND and NOR-NOR realizations.

UNIT – II: MINIMIZATION TECHNIQUES

Boolean theorems, principle of complementation & duality, De-morgan theorems, minimization of logic functions using Boolean theorems, minimization of switching functions using K-Map up to 6 variables, tabular minimization, problem solving (code-converters using K-Map etc..).

UNIT – III: COMBINATIONAL LOGIC CIRCUITS DESIGN

Design of Half adder, full adder, half subtractor, full subtractor, applications of full adders, 4-bit binary subtractor, adder-subtractor circuit, BCD adder circuit, Excess 3 adder circuit, look-a-head adder circuit, Design of decoder, demultiplexer, 7 segment decoder, higher order demultiplexing, encoder, multiplexer, higher order multiplexing, realization of Boolean functions using decoders and multiplexers, priority encoder, 4-bit digital comparator.

UNIT – IV: INTRODUCTION OF PLD's

PROM, PAL, PLA-Basics structures, realization of Boolean function with PLDs, programming tables of PLDs, merits & demerits of PROM, PAL, PLA comparison, realization of Boolean functions using PROM, PAL, PLA, programming tables of PROM, PAL, PLA.

UNIT – V: SEQUENTIAL CIRCUITS I

Classification of sequential circuits (synchronous and asynchronous); basic flip-flops, truth tables and excitation tables (nand RS latch, nor RS latch, RS flip-flop, JK flip-flop, T flip-flop, D flip-flop with reset and clear terminals). Conversion from one flip-flop to flip-flop. Design of ripple counters, design of synchronous counters, Johnson counter, ring counter. Design of registers - Buffer register, control buffer register, shift register, bi-directional shift register, universal shift register.

UNIT – VI: SEQUENTIAL CIRCUITS II

Finite state machine; Analysis of clocked sequential circuits, state diagrams, state tables, reduction of state tables and state assignment, design procedures. Realization of circuits using various flip-flops. Meelay to Moore conversion and vice-versa.

TEXT BOOKS:

1. Switching Theory and Logic Design by Hill and Peterson Mc-Graw Hill TMH edition.
2. Switching Theory and Logic Design by A. Anand Kumar
3. Digital Design by Mano PHI.

REFERENCE BOOKS:

1. Modern Digital Electronics by RP Jain, TMH
2. Fundamentals of Logic Design by Charles H. Roth Jr, Jaico Publishers
3. Micro electronics by Milliman MH edition.

II Year - I Semester

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SIGNALS & SYSTEMS

OBJECTIVES:

The main objectives of this course are given below:

- To introduce the terminology of signals and systems.
- To introduce Fourier tools through the analogy between vectors and signals.
- To introduce the concept of sampling and reconstruction of signals.
- To analyze the linear systems in time and frequency domains.
- To study z-transform as mathematical tool to analyze discrete-time signals and systems.

UNIT- I: INTRODUCTION: Definition of Signals and Systems, Classification of Signals, Classification of Systems, Operations on signals: time-shifting, time-scaling, amplitude-shifting, amplitude-scaling. Problems on classification and characteristics of Signals and Systems. Complex exponential and sinusoidal signals, Singularity functions and related functions: impulse function, step function signum function and ramp function. Analogy between vectors and signals, orthogonal signal space, Signal approximation using orthogonal functions, Mean square error, closed or complete set of orthogonal functions, Orthogonality in complex functions.

UNIT –II: FOURIER SERIES AND FOURIER TRANSFORM:

Fourier series representation of continuous time periodic signals, properties of Fourier series, Dirichlet's conditions, Trigonometric Fourier series and Exponential Fourier series, Complex Fourier spectrum. Deriving Fourier transform from Fourier series, Fourier transform of arbitrary signal, Fourier transform of standard signals, Fourier transform of periodic signals, properties of Fourier transforms, Fourier transforms involving impulse function and Signum function. Introduction to Hilbert Transform.

UNIT –III: SAMPLING THEOREM – Graphical and analytical proof for Band Limited Signals, impulse sampling, Natural and Flat top Sampling, Reconstruction of signal from its samples, effect of under sampling – Aliasing, Introduction to Band Pass sampling.

UNIT-IV: ANALYSIS OF LINEAR SYSTEMS: Linear system, impulse response, Response of a linear system, Linear time invariant (LTI) system, Linear time variant (LTV) system, Concept of convolution in time domain and frequency domain, Graphical representation of convolution, Transfer function of a LTI system. Filter characteristics of linear systems. Distortion less transmission through a system, Signal bandwidth, system bandwidth, Ideal LPF, HPF and BPF characteristics, Causality and Poly-Wiener criterion for physical realization, relationship between bandwidth and rise time.

Cross-correlation and auto-correlation of functions, properties of correlation function, Energy density spectrum, Parseval's theorem, Power density spectrum, Relation between auto correlation function and energy/power spectral density function. Relation between convolution and correlation, Detection of periodic signals in the presence of noise by correlation, Extraction of signal from noise by filtering.

UNIT –V: LAPLACE TRANSFORMS : Review of Laplace transforms, Partial fraction expansion, Inverse Laplace transform, Concept of region of convergence (ROC) for Laplace transforms, constraints on ROC for various classes of signals, Properties of L.T's, Relation between L.T's, and F.T. of a signal. Laplace transform of certain signals using waveform synthesis.

UNIT –VI: Z–TRANSFORMS : Fundamental difference between continuous-time and discrete-time signals, discrete time signal representation using complex exponential and sinusoidal components, Periodicity of discrete time using complex exponential signal, Concept of Z- Transform of a discrete sequence. Distinction between Laplace, Fourier and Z transforms. Region of convergence in Z-Transform, constraints on ROC for various classes of signals, Inverse Z-transform, properties of Z-transforms.

TEXT BOOKS:

1. Signals, Systems & Communications - B.P. Lathi, BS Publications, 2003.
2. Signals and Systems - A.V. Oppenheim, A.S. Willsky and S.H. Nawab, PHI, 2nd Edn.
3. Signals & Systems- Narayan Iyer and K Satya Prasad, Cenage Pub.

REFERENCE BOOKS:

1. Signals & Systems - Simon Haykin and Van Veen, Wiley, 2nd Edition.
2. Principles of Linear Systems and Signals – BP Lathi, Oxford University Press, 2015
3. Signals and Systems – K Raja Rajeswari, B VisweswaraRao, PHI, 2009
4. Fundamentals of Signals and Systems- Michel J. Robert, MGH International Edition, 2008.
5. Signals and Systems – T K Rawat , Oxford University press, 2011

OUTCOMES:

At the end of this course the student will able to:

- Characterize the signals and systems and principles of vector spaces, Concept of orthogonality.
- Analyze the continuous-time signals and continuous-time systems using Fourier series, Fourier transform and Laplace transform.
- Apply sampling theorem to convert continuous-time signals to discrete-time signal and reconstruct back.
- Understand the relationships among the various representations of LTI systems
- Understand the Concepts of convolution, correlation, Energy and Power density spectrum and their relationships.
- Apply z-transform to analyze discrete-time signals and systems.

II Year - I Semester

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RANDOM VARIABLES & STOCHASTIC PROCESSES

OBJECTIVES:

- To give students an introduction to elementary probability theory, in preparation for courses on statistical analysis, random variables and stochastic processes.
- To mathematically model the random phenomena with the help of probability theory concepts.
- To introduce the important concepts of random variables and stochastic processes.
- To analyze the LTI systems with stationary random process as input.
- To introduce the types of noise and modelling noise sources.

UNIT I

THE RANDOM VARIABLE : Introduction, Review of Probability Theory, Definition of a Random Variable, Conditions for a Function to be a Random Variable, Discrete, Continuous and Mixed Random Variables, Distribution and Density functions, Properties, Binomial, Poisson, Uniform, Gaussian, Exponential, Rayleigh, Conditional Distribution, Conditional Density, Properties.

UNIT II

OPERATION ON ONE RANDOM VARIABLE – EXPECTATIONS : Introduction, Expected Value of a Random Variable, Function of a Random Variable, Moments about the Origin, Central Moments, Variance and Skew, Chebychev's Inequality, Characteristic Function, Moment Generating Function, Transformations of a Random Variable: Monotonic Transformations for a Continuous Random Variable, Nonmonotonic Transformations of Continuous Random Variable.

UNIT III

MULTIPLE RANDOM VARIABLES : Vector Random Variables, Joint Distribution Function, Properties of Joint Distribution, Marginal Distribution Functions, Conditional Distribution and Density, Statistical Independence, Sum of Two Random Variables, Sum of Several Random Variables, Central Limit Theorem: Unequal Distribution, Equal Distributions.

OPERATIONS ON MULTIPLE RANDOM VARIABLES: Joint Moments about the Origin, Joint Central Moments, Joint Characteristic Functions, Jointly Gaussian Random Variables: Two Random Variables case, N Random Variables case, Properties, Transformations of Multiple Random Variables, Linear Transformations of Gaussian Random Variables.

UNIT IV

RANDOM PROCESSES – TEMPORAL CHARACTERISTICS: The Random Process Concept, Classification of Processes, Deterministic and Nondeterministic Processes, Distribution and Density Functions, Concept of Stationarity and Statistical Independence. First-Order Stationary Processes, Second-order and Wide-Sense Stationarity, N^{th} -order and Strict-Sense Stationarity, Time Averages and Ergodicity, Autocorrelation Function and its Properties, Cross-Correlation Function and its Properties, Covariance Functions, Gaussian Random Processes, Poisson Random Process.

UNIT V

RANDOM PROCESSES – SPECTRAL CHARACTERISTICS: The Power Density Spectrum: Properties, Relationship between Power Density Spectrum and Autocorrelation Function, The Cross-Power Density Spectrum, Properties, Relationship between Cross-Power Density Spectrum and Cross-Correlation Function.

UNIT VI

LINEAR SYSTEMS WITH RANDOM INPUTS : Random Signal Response of Linear Systems: System Response – Convolution, Mean and Mean-squared Value of System Response, Autocorrelation Function of Response, Cross-Correlation Functions of Input and Output, Spectral Characteristics of System Response: Power Density Spectrum of Response, Cross-Power Density Spectra of Input and Output, Band pass, Band-Limited and Narrowband Processes, Properties, Modeling of Noise Sources: Resistive (Thermal) Noise Source, Arbitrary Noise Sources, Effective Noise Temperature, Average Noise Figure, Average Noise Figure of cascaded networks.

TEXT BOOKS:

1. Probability, Random Variables & Random Signal Principles, Peyton Z. Peebles, TMH, 4th Edition, 2001.
2. Probability, Random Variables and Stochastic Processes, Athanasios Papoulis and S.Unnikrishna, PHI, 4th Edition, 2002.

REFERENCE BOOKS:

1. Probability Theory and Stochastic Processes – B. Prabhakara Rao, BS Publications
2. Probability and Random Processes with Applications to Signal Processing, Henry Stark and John W. Woods, Pearson Education, 3rd Edition.
3. Schaum's Outline of Probability, Random Variables, and Random Processes.
4. An Introduction to Random Signals and Communication Theory, B.P. Lathi, International Textbook, 1968.
5. Random Process – Ludeman , John Wiley
6. Probability Theory and Random Processes, P. Ramesh Babu, McGrawHill, 2015.

OUTCOMES:

After completion of the course, the student will be able to

- Mathematically model the random phenomena and solve simple probabilistic problems.
- Identify different types of random variables and compute statistical averages of these random variables.
- Characterize the random processes in the time and frequency domains.
- Analyze the LTI systems with random inputs.
- Apply these techniques to analyze the systems in the presence of different types of noise.

II Year - I Semester

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ELECTRONIC DEVICES AND CIRCUITS LAB

Note: The students are required to perform the experiment to obtain the V-I characteristics and to determine the relevant parameters from the obtained graphs.

Electronic Workshop Practice:

1. Identification, Specifications, Testing of R, L, C Components (Colour Codes), Potentiometers, Coils, Gang Condensers, Relays, Bread Boards.
2. Identification, Specifications and Testing of active devices, Diodes, BJTs, JFETs, LEDs, LCDs, SCR, UJT.
3. Soldering Practice- Simple circuits using active and passive components.
4. Study and operation of Ammeters, Voltmeters, Transformers, Analog and Digital Multimeter, Function Generator, Regulated Power Supply and CRO..

List of Experiments: (Minimum of Ten Experiments has to be performed)

1. P-N Junction Diode Characteristics
Part A: Germanium Diode (Forward bias & Reverse bias)
Part B: Silicon Diode (Forward Bias only)
2. Zener Diode Characteristics
Part A: V-I Characteristics
Part B: Zener Diode as Voltage Regulator
3. Rectifiers (without and with c-filter)
Part A: Half-wave Rectifier
Part B: Full-wave Rectifier
4. BJT Characteristics (CE Configuration)
Part A: Input Characteristics
Part B: Output Characteristics
5. FET Characteristics (CS Configuration)
Part A: Drain Characteristics
Part B: Transfer Characteristics
6. SCR Characteristics
7. UJT Characteristics
8. Transistor Biasing
9. CRO Operation and its Measurements
10. BJT-CE Amplifier
11. Emitter Follower-CC Amplifier
12. FET-CS Amplifier

Equipment required:

1. Regulated Power supplies
2. Analog/Digital Storage Oscilloscopes
3. Analog/Digital Function Generators
4. Digital Multimeters
5. Decade Résistance Boxes/Rheostats
6. Decade Capacitance Boxes
7. Ammeters (Analog or Digital)
8. Voltmeters (Analog or Digital)
9. Active & Passive Electronic Components

II Year - I Semester

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NETWORKS & ELECTRICAL TECHNOLOGY LAB

Learning Objectives:

- To determine resonance frequency, Q-factor of RLC network.
- To analysis time response of first orders RC/RL network for non-sinusoidal inputs.
- To estimate parameters of two port networks
- To understand the concept network theorems in network reduction of electrical networks.
- To determine efficiency of dc shunt machine with actual loading.
- To analyse performance of 3 phase induction motor
- To understand the significance of regulation of an alternators through synchronous impedance method.

PART – A

Any five experiments are to be conducted from each part

1. Series and Parallel Resonance – Timing, Resonant frequency, Bandwidth and Q-factor determination for RLC network.
2. Time response of first order RC/RL network for periodic non-sinusoidal inputs – time constant and steady state error determination.
3. Two port network parameters – Z-Y Parameters, chain matrix and analytical verification.
4. Verification of Superposition and Reciprocity theorems.
5. Verification of maximum power transfer theorem. Verification on DC, verification on AC with Resistive and Reactive loads.
6. Experimental determination of Thevenin's and Norton's equivalent circuits and verification by direct test.

PART – B

1. Magnetization characteristics of D.C. Shunt generator. Determination of critical field resistance.
2. Speed control of D.C. Shunt motor by Armature & flux control methods
3. Brake test on DC shunt motor. Determination of performance characteristics.
4. OC & SC tests on Single-phase transformer (Predetermination of efficiency and regulation at given power factors and determination of equivalent circuit).
5. Brake test on 3-phase Induction motor (performance characteristics).
6. Regulation of alternator by synchronous impedance method

Learning Outcomes:

- Able to analyse RLC circuits and understand resonant frequency and Q-factor.
- Able to determine first order RC/RL networks of periodic non- sinusoidal waveforms.
- Able to apply network theorems to analyze the electrical network.
- Able to describe the performance of dc shunt machine.
- Able to investigate the performance of 1-phase transformer.
- Able to perform tests on 3-phase induction motor and alternator to determine their performance characteristic

